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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of :

Takatomo SASAKI et al. :

Attn: BOX PCT

Serial No. NEW :

Docket No. 2001\_1739A

Filed November 23, 2001 :

THE COMMISSIONER IS AUTHORIZED  
TO CHARGE ANY DEFICIENCY IN THE  
FEES FOR THIS PAPER TO DEPOSIT  
ACCOUNT NO. 23-0975METHOD AND APPARATUS FOR GROWING  
HIGH QUALITY SINGLE CRYSTAL[Corresponding to PCT/JP00/03264  
Filed May 22, 2000]PRELIMINARY AMENDMENT TO REDUCE PTO FILING FEEAssistant Commissioner for Patents,  
Washington, DC 20231

Sir:

Please amend the above-identified application as follows.

In the Claims:

Kindly amend claims 5 and 15 as follows.

A1 5. (Amended) A method according to claim 3, wherein a single crystal of an oxide is grown.

A2 15. (Amended) An apparatus for growing a single crystal of an oxide comprising the growing apparatus as claimed in claim 13.

ATTACHMENT E